General Description

The MAX2630/MAX2631/MAX2632/MAX2633 are lowvoltage. low-noise amplifiers for use from VHF to microwave frequencies. Operating from a single +2.7V to +5.5V supply, these devices have a flat gain response to 900MHz. Their low noise figure and low supply current make them ideal for receive, buffer, and transmit IF applications.

The MAX2630/MAX2631 are biased internally, eliminating the need for external bias resistors or inductors. The MAX2632/MAX2633 have a user-selectable supply current, which can be adjusted by adding a single external resistor. This allows customized output power and gain according to specific applications requirements. The MAX2631/MAX2633 feature a shutdown pin that allows them to be powered down to less than 1µA supply current. Aside from a single bias resistor required for the MAX2632/MAX2633, the only external components needed for this family of amplifiers are input and output blocking capacitors and a VCC bypass capacitor.

The MAX2630 comes in a 4-pin SOT143 package, requiring minimal board space. The MAX2631/MAX2632 come in small 5-pin SOT23 packages. The MAX2633 comes in a 6-pin SOT23 package.

	_Applications
Personal Communicating Systems	Cordless Phones
Global Positioning Systems	Cellular Phones
Wireless Local Area Networks	ISM Radios
Wireless Local Loops	TV Tuners
Land Mobile Radios	Set-Top Boxes

Typical Operating Circuit GND 2 3 IN OUT 3 4 V_{CC} **SOT143** SOT23-5 CBLOCK IN SHDN BIAS 1 BIAS MIXIM MIXIM 6 IN 5 IN SHDN 11 MAX2632 MAX2633 RBIAS GND BIAS GND 2 GND 2 5 BIAS AABI AAA OUT Vcc OUT 3 4 V_{CC} OUT 3 MAXIM CBLOCK MAX2633 SOT23-5 SOT23-6

M/X/M

Maxim Integrated Products 1

Single +2.7V to +5.5V Operation Internally Biased (MAX2630/MAX2631)

- Adjustable Bias (MAX2632/MAX2633)
- ♦ 6.6mA Supply Current (insensitive to supply voltage)
- 1µA Shutdown Current (MAX2631/MAX2633)
- ♦ 3.7dB Noise Figure
- 13.4dB Gain

TOP VIFW

OUT

MAXIM

MAX2630

DG

Ultra-Small SOT Packages

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	SOT TOP MARK*
MAX2630EUS-T	-40°C to +85°C	4 SOT143-4	DG
MAX2631 EUK-T	-40°C to +85°C	5 SOT23-5	AABK
MAX2632EUK-T	-40°C to +85°C	5 SOT23-5	AABL
MAX2633EUT-T	-40°C to +85°C	6 SOT23-6	AAAA

*The first two letters in the SOT top mark identify the part. while the remaining two letters are the lot-tracking code.

4 V_{CC}

SHDN

GND 2

Pin Configurations

MIXIM

MAX2631

AABK

5 IN

4 V_{CC}

Features

ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND	-0.3V to 6V
Input Power	
OUT Current	
IN to GND Voltage	1.2V to 1.2V
Bias to GND Voltage	0.0V to 3V
Voltage at SHDN Input	
(MAX2631/MAX2633)	0.3V to (V _{CC} + 0.3V)
Current into SHDN Input (MAX2631	/MAX2633)100µA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
SOT143 (derate 4mW/°C above +70°C)	320mW
SOT23-5 (derate 7.1mW/°C above +70°C).	571mW
SOT23-6 (derate 7.1mW/°C above +70°C).	571mW
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION! ESD SENSITIVE DEVICE

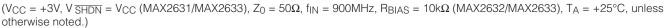
ELECTRICAL CHARACTERISTICS

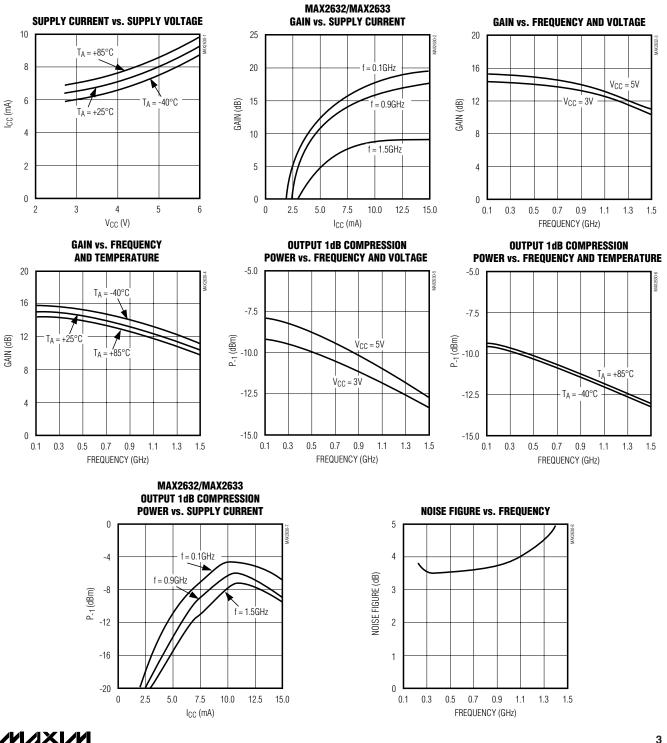
 $(V_{CC} = +3V, Z_0 = 50\Omega, f_{IN} = 900MHz, R_{BIAS} = 10k\Omega \text{ (MAX2632/MAX2633), } V_{\overline{SHDN}} = V_{CC} \text{ (MAX2631/MAX2633), } T_A = +25^{\circ}C, \text{ unless otherwise noted.)}$

PARAMETERS		(CONDITIONS	MIN	ТҮР	MAX	UNITS
Operating Temperature Range	(Note 1)			-40		85	degrees
Supply Voltage				2.7		5.5	V
Power Gain	$T_A = +25^{\circ}C$			11	13.4	16.5	dB
	$T_A = T_{MIN}$ to T	Гмах ((Note 1)	9.4		18.4	UD UD
Noise Figure					3.8		dB
Output 1dB Compression Point					-11		dBm
Output IP3					-1		dBm
Input Voltage Standing-Wave Ratio	$f_{IN} = 800MHz$	to 10	00MHz		1.3:1		
Output Voltage Standing-Wave Ratio	$f_{IN} = 800MHz$		1.25:1				
	$R_{BIAS} = 40k\Omega$		1.3	1.5			
	$R_{BIAS} = 10k\Omega$	Vcc	$c = 3V, T_A = +25^{\circ}C$	5.5	6.5	8.0	
Supply Current		Vcc	$c = 3V, T_A = T_{MIN}$ to T_{MAX} (Note1)	4.2	6.5	9.2	mA
		Vcc	$c = 2.7V$ to 5.5V, $T_A = +25^{\circ}C$	5.2	6.5	11.0	
	$R_{BIAS} = 500\Omega$	2		15	17		
Shutdown Supply Current	MAX2631/MA	X2633	3		<0.1	1	μΑ
SHDN Input Low Voltage	MAX2631/MA	X2633	3, $V_{CC} = 2.7V$ to 5.5V			0.45	V
SHDN Input High Voltage	MAX2631/MA	X2633	3, $V_{CC} = 2.7V$ to 5.5V	2.0			V
	MAX2631/ MAX2633		$V_{\overline{SHDN}} = V_{CC}$			30	μA
SHDN Input Bias Current			V _{SHDN} = GND			1	μA

Note 1: Guaranteed by design and characterization.

Typical Operating Characteristics

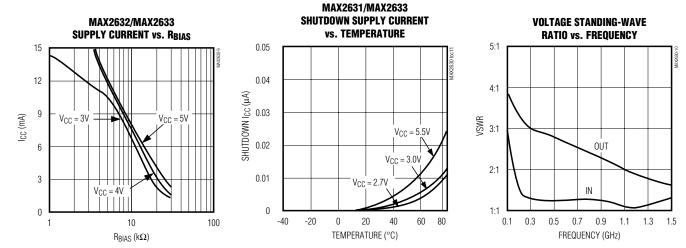




3



 $(V_{CC} = +3V, V \overline{SHDN} = V_{CC} (MAX2631/MAX2633), Z_0 = 50\Omega, f_{IN} = 900MHz, R_{BIAS} = 10k\Omega (MAX2632/MAX2633), T_A = +25^{\circ}C, unless otherwise noted.)$



Pin Description

PIN				NAME	FUNCTION
MAX2630	MAX2631	MAX2632	MAX2633	NAME	FUNCTION
3	5	5	6	IN	Amplifier Input. Use a series blocking capacitor with less than 3Ω reactance at your lowest operating frequency.
2	2	2	2	GND	Ground Connection. For optimum performance, provide a low- inductance connection to the ground plane.
1	3	3	3	OUT	Amplifier Output. Use a series blocking capacitor with less than 3Ω reactance at your lowest operating frequency.
4	4	4	4	Vcc	Supply Connection. Bypass directly at the supply pin. The value of the bypass capacitor is determined by the lowest operating frequency, and is typically the same as the blocking capacitor value. Additional bypassing may be necessary for long V_{CC} lines.
	1	_	1	SHDN	Shutdown Input. Driving SHDN with a logic low turns off the amplifier.
		1	5	BIAS	Bias Resistor Connection. Connect a resistor to GND to set the bias current. See the Supply Current vs. R _{BIAS} graph in the <i>Typical Operating Characteristics</i> .



MAX2630-MAX2633

Table 1a. Typical Scattering Parameters

FREQUENCY (GHz)	S11 (mag)	S11 (ang)	S21 (dB)	S21 (mag)	S21 (ang)	S12 (dB)	S12 (mag)	S12 (ang)	S22 (mag)	S22 (ang)	к
0.05	0.59	-50	12.9	4.39	46	-38.7	0.012	37	0.62	-19	4.30
0.10	0.37	-70	14.2	5.11	1	-36.7	0.015	12	0.57	-29	4.07
0.20	0.22	-86	14.5	5.32	-49	-35.8	0.016	-13	0.54	-49	3.93
0.30	0.17	-100	14.5	5.32	-89	-35.0	0.018	-32	0.53	-71	3.74
0.40	0.16	-109	14.5	5.28	-125	-34.4	0.019	-51	0.51	-94	3.61
0.50	0.15	-99	14.3	5.19	-138	-33.6	0.021	-70	0.50	-118	3.45
0.60	0.14	-86	14.1	5.05	-127	-33.0	0.022	-89	0.48	-109	3.38
0.70	0.14	-68	13.9	4.93	-116	-32.2	0.025	-107	0.46	-96	3.27
0.80	0.14	-49	13.5	4.75	-104	-31.3	0.027	-124	0.44	-82	3.16
0.90	0.13	-31	13.0	4.49	-93	-30.3	0.031	-142	0.42	-68	3.05
1.00	0.13	-10	12.6	4.25	-82	-29.0	0.035	-161	0.40	-53	2.87
1.20	0.06	19	10.8	3.48	-58	-25.8	0.051	153	0.33	-25	2.59
1.40	0.11	-60	7.9	2.48	-110	-23.7	0.065	113	0.26	-12	2.90
1.60	0.24	-31	5.6	1.91	-162	-23.6	0.066	122	0.26	-7	3.51
1.80	0.30	-26	4.8	1.73	144	-23.7	0.065	120	0.26	-34	3.76
2.00	0.31	-66	4.3	1.63	86	-23.3	0.069	117	0.25	-63	3.80
2.20	0.27	-98	3.6	1.51	27	-22.3	0.077	116	0.24	-83	3.80
2.40	0.24	-115	2.6	1.36	5	-21.3	0.086	116	0.25	-97	3.81
2.50	0.22	-120	2.2	1.29	12	-21.0	0.089	114	0.27	-106	3.86

Table 1b. MAX2633 Typical Scattering Parameters

 $(V_{CC}=+5V, V_{\overline{SHDN}}=V_{CC}, Z_0=50\Omega, R_{BIAS}=10k, T_A=+25^{\circ}C.)$

FREQUENCY (GHz)	S11 (mag)	S11 (ang)	S21 (dB)	S21 (mag)	S21 (ang)	S12 (dB)	S12 (mag)	S12 (ang)	S22 (mag)	S22 (ang)	к
0.05	0.58	-53	13.6	4.80	45	-39.2	0.011	36	0.62	-22	4.26
0.10	0.35	-76	15.0	5.62	1	-36.9	0.014	13	0.57	-29	3.83
0.20	0.20	-97	15.4	5.87	-48	-36.1	0.016	-14	0.55	-49	3.75
0.30	0.14	-101	15.4	5.91	-87	-35.2	0.017	-31	0.53	-72	3.48
0.40	0.12	-94	15.4	5.91	-123	-34.7	0.018	-50	0.52	-95	3.35
0.50	0.11	-82	15.4	5.87	-141	-33.8	0.020	-68	0.51	-119	3.14
0.60	0.11	-66	15.2	5.78	-130	-33.1	0.022	-86	0.49	-108	3.02
0.70	0.11	-45	15.1	5.68	-119	-32.3	0.024	-104	0.48	-94	2.87
0.80	0.11	-22	14.9	5.54	-108	-31.3	0.027	-121	0.45	-79	2.73
0.90	0.12	-2	14.5	5.30	-96	-30.0	0.032	-139	0.43	-65	2.51
1.00	0.12	21	14.1	5.09	-85	-28.5	0.038	-158	0.42	-49	2.28
1.20	0.08	-54	12.5	4.22	-59	-25.2	0.055	153	0.34	-18	2.01
1.40	0.10	-103	9.3	2.93	-112	-23.1	0.070	114	0.24	-4	2.36
1.60	0.22	-44	6.7	2.16	-163	-23.3	0.068	125	0.24	-7	3.07
1.80	0.29	-20	5.8	1.96	145	-23.7	0.065	124	0.24	-37	3.41
2.00	0.30	-60	5.3	1.85	89	-23.3	0.069	120	0.23	-65	3.41
2.20	0.26	-92	4.9	1.75	29	-22.2	0.078	117	0.21	-83	3.31
2.40	0.24	-110	3.9	1.57	2	-21.7	0.082	116	0.23	-95	3.48
2.50	0.23	-113	3.5	1.50	10	-20.9	0.090	115	0.25	-100	3.35

Detailed Description

The MAX2630–MAX2633 are broadband amplifiers with 3dB bandwidth greater than 1GHz. Their small size and internal bias circuitry make them ideal for applications where board space is limited. The MAX2632/MAX2633 have a user-selectable bias current that allows the user to set both gain and output power for a particular application, and the MAX2631/MAX2633 incorporate shutdown capability.

Applications Information

External Components

The MAX2630–MAX2633 are easy to use, as shown in the *Typical Operating Circuit* and Figures 1, 2 and 3. Input and output series capacitors may be necessary to block DC bias voltages generated by the amplifiers from interacting with adjacent circuitry. These capacitors must be large enough to contribute negligible reactance in a 50 Ω system at the minimum operating frequency. Use the following equation to calculate their minimum value:

$$C_{BLOCK} = \frac{53,000}{f} \text{ (pF)}$$

where f (in megahertz) is the minimum operating frequency.

The V_{CC} pin must be RF bypassed for correct operation. To accomplish this, connect a capacitor between the V_{CC} pin and ground, as close to the package as is practical. Use the same equation given above (for DCblocking capacitor values) to calculate the minimum capacitor value. If the PC board has long V_{CC} lines, additional bypassing may be necessary. This can be done farther away from the package, if needed.

Proper grounding of the GND pin is essential. If the PC board uses a topside RF ground, connect it directly to the GND pin. For a board where the ground plane is not on the component side, the best technique is to connect the GND pin to it with a plated through-hole close to the package.

An on-chip buffer at the MAX2631/MAX2633's SHDN pin makes bypassing this pin unnecessary except in very noisy applications. When RF filtering is needed, use a bypass capacitor similar to the one used on V_{CC}. Since negligible current flows into this pin, additional RF filtering may be done with a series resistor.

To set the MAX2632/MAX2633's supply current, connect a resistor from the BIAS pin to ground. To estimate the value of this resistor, refer to the graph Supply Current vs. R_{BIAS} in the *Typical Operating Characteristics*.

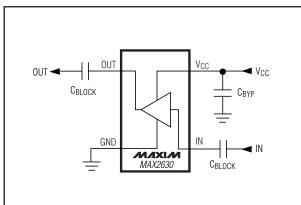


Figure 1. MAX2630 Typical Operating Circuit

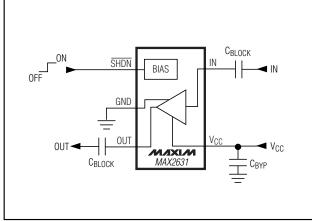


Figure 2. MAX2631 Typical Operating Circuit

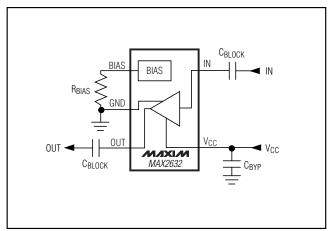


Figure 3. MAX2632 Typical Operating Circuit

PC Board Layout Example

Example PC board layouts are given in Figures 4 to 7. They use FR-4 with a 31mil layer thickness between the RF lines and the ground plane. The boards satisfy all of the above recommendations.

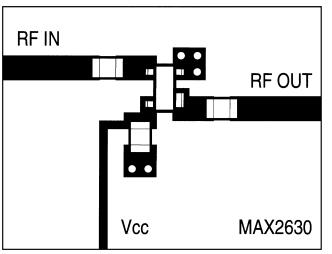
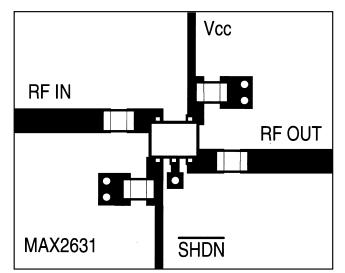


Figure 4. MAX2630 Example PC Board Layout





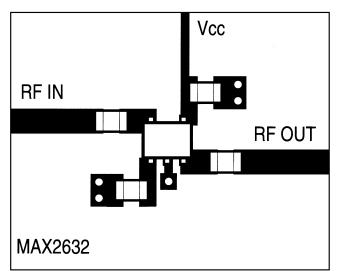
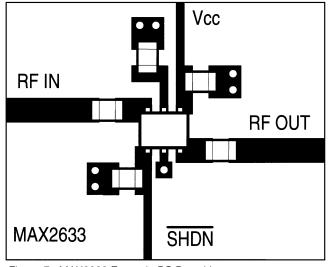
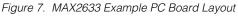


Figure 6. MAX2632 Example PC Board Layout

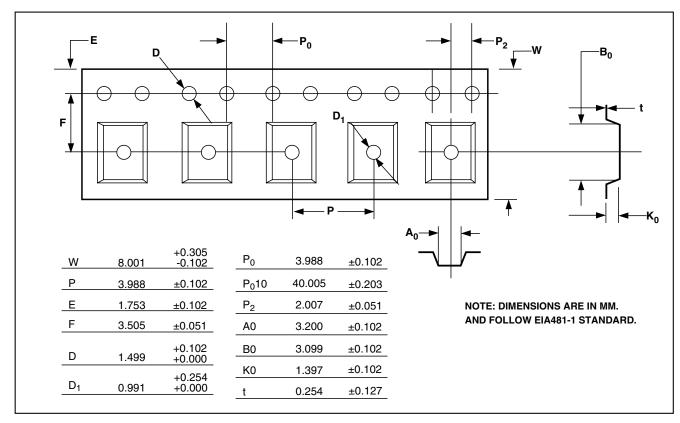




Chip Information

TRANSISTOR COUNT: 199



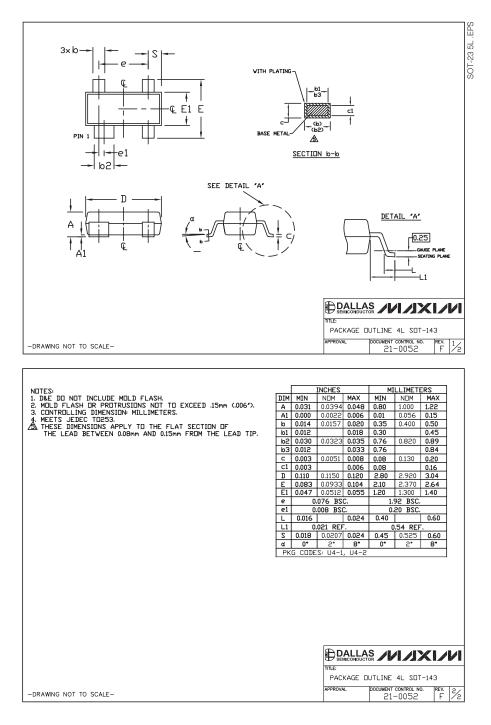


Revision History

Pages changed at Rev 3: 1, 4, 9-12.

Package Information

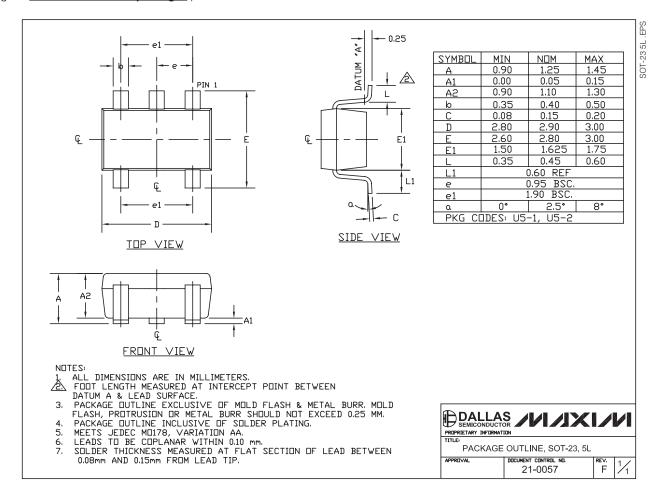
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)



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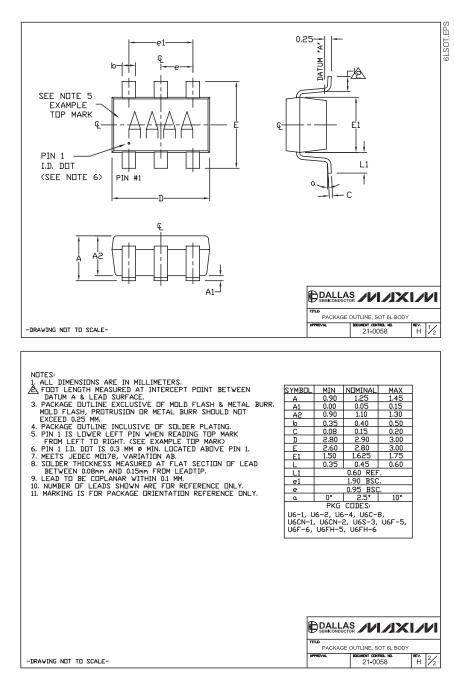
Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)



Package Information (continued)

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